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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

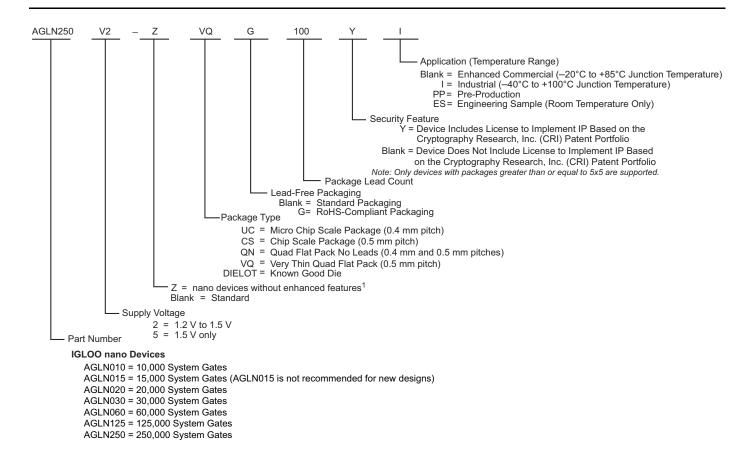
The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	1536
Total RAM Bits	18432
Number of I/O	71
Number of Gates	60000
Voltage - Supply	1.14V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/agln060v2-zvqg100i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

IGLOO nano Ordering Information



Notes:

- Z-feature grade devices AGLN060Z, AGLN125Z, and AGLN250Z do not support the enhanced nano features of Schmitt Trigger input, bus hold (hold previous I/O state in Flash*Freeze mode), cold-sparing, hot-swap I/O capability and 1.2 V programming. The AGLN030 Z feature grade does not support Schmitt trigger input, bus hold and 1.2 V programming. For the VQ100, CS81, UC81, QN68, and QN48 packages, the Z feature grade and the N part number are not marked on the device. Z feature grade devices are not recommended for new designs.
- AGLN030 is available in the Z feature grade only.
- 3. Marking Information: IGLOO nano V2 devices do not have a V2 marking, but IGLOO nano V5 devices are marked with a V5 designator.

Devices Not Recommended For New Designs

AGLN015, AGLN030Z, AGLN060Z, AGLN125Z, and AGLN250Z are not recommended for new designs. For more information on obsoleted devices/packages, refer to the *PDN1503 - IGLOO nano Z and ProASIC3 nano Z Families*.

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Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode*

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
VCCI= 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μΑ
VCCI = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μΑ
VCCI = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μΑ
VCCI = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μΑ
VCCI = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μΑ

Note: $*I_{DD} = N_{BANKS} * I_{CCI}$.

Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Shutdown Mode

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
Typical (25°C)	1.2 V / 1.5 V	0	0	0	0	0	0	μА

Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash*Freeze Mode¹

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
ICCA Current ²								
Typical (25°C)	1.2 V	3.7	5	5	10	13	18	μA
	1.5 V	8	14	14	20	28	44	μΑ
ICCI or IJTAG Current								
VCCI / VJTAG = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μA
VCCI / VJTAG = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μA
VCCI / VJTAG = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μA
VCCI / VJTAG = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μA
VCCI / VJTAG = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μA

Notes:

- IDD = N_{BANKS} * ICCI + ICCA. JTAG counts as one bank when powered.
 Includes VCC, VCCPLL, and VPUMP currents.

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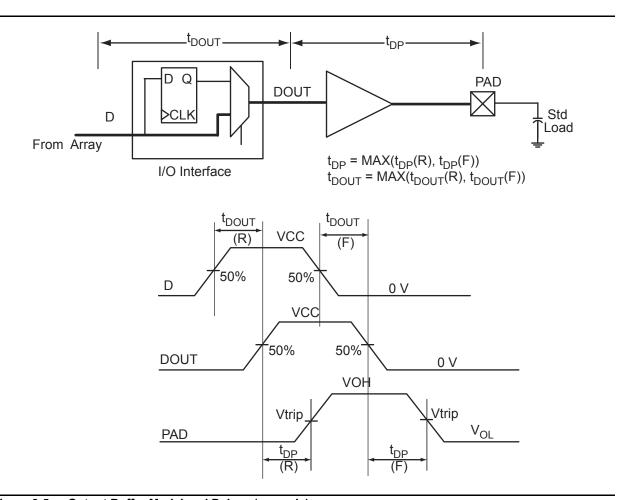


Figure 2-5 • Output Buffer Model and Delays (example)

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Applies to IGLOO nano at 1.2 V Core Operating Conditions

Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings
STD Speed Grade, Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equiv. Software Default Drive Strength Option ¹	Slew Rate	Capacitive Load (pF)	tвоит	t _{DP}	t _{DIN}	tpy)	t _{PYS}	^t Eo∪T	tzı	tzн	t _{LZ}	thz	Units
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.31	0.26	0.97	1.36	1.10	2.34	1.90	2.43	3.14	ns
3.3 V LVCMOS Wide Range ²	100 μΑ	8 mA	High	5 pF	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
2.5 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
1.8 V LVCMOS	4 mA	4 mA	High	5 pF	1.55	2.49	0.26	1.13	1.59	1.10	2.53	2.34	2.42	2.81	ns
1.5 V LVCMOS	2 mA	2 mA	High	5 pF	1.55	2.78	0.26	1.27	1.77	1.10	2.82	2.62	2.44	2.74	ns
1.2 V LVCMOS	1 mA	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns
1.2 V LVCMOS Wide Range ³	100 μΑ	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns

Notes:

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
- 3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V side range as specified in the JESD8-12 specification.
- 4. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-41 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	0.97	5.23	0.19	1.20	1.66	0.66	5.24	5.00	2.47	2.56	ns
100 μΑ	4 mA	STD	0.97	5.23	0.19	1.20	1.66	0.66	5.24	5.00	2.47	2.56	ns
100 μΑ	6 mA	STD	0.97	4.27	0.19	1.20	1.66	0.66	4.28	4.12	2.83	3.16	ns
100 μΑ	8 mA	STD	0.97	4.27	0.19	1.20	1.66	0.66	4.28	4.12	2.83	3.16	ns

Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-42 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	0.97	3.11	0.19	1.20	1.66	0.66	3.13	2.55	2.47	2.70	ns
100 μΑ	4 mA	STD	0.97	3.11	0.19	1.20	1.66	0.66	3.13	2.55	2.47	2.70	ns
100 μΑ	6 mA	STD	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns
100 μΑ	8 mA	STD	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns

Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

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Applies to 1.2 V DC Core Voltage

Table 2-49 • 2.5 LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
4 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
6 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns
8 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-50 • 2.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
4 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
6 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
8 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-53 • 1.8 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t_{LZ}	t _{HZ}	Units
2 mA	STD	0.97	5.44	0.19	1.03	1.44	0.66	5.25	5.44	1.69	1.35	ns
4 mA	STD	0.97	4.44	0.19	1.03	1.44	0.66	4.37	4.44	1.99	2.11	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-54 • 1.8 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.64	0.19	1.03	1.44	0.66	2.59	2.64	1.69	1.40	ns
4 mA	STD	0.97	2.08	0.19	1.03	1.44	0.66	2.12	1.95	1.99	2.19	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-55 • 1.8 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	5.92	0.26	1.13	1.59	1.10	5.72	5.92	2.11	1.95	ns
4 mA	STD	1.55	4.91	0.26	1.13	1.59	1.10	4.82	4.91	2.42	2.73	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-56 • 1.8 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	3.05	0.26	1.13	1.59	1.10	3.01	3.05	2.10	2.00	ns
4 mA	STD	1.55	2.49	0.26	1.13	1.59	1.10	2.53	2.34	2.42	2.81	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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1.2 V DC Core Voltage

Table 2-87 • Register Delays

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{CLKQ}	Clock-to-Q of the Core Register	1.61	ns
t _{SUD}	Data Setup Time for the Core Register	1.17	ns
t_{HD}	Data Hold Time for the Core Register	0.00	ns
t _{SUE}	Enable Setup Time for the Core Register	1.29	ns
t _{HE}	Enable Hold Time for the Core Register	0.00	ns
t _{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.87	ns
t _{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.89	ns
t _{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t _{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t _{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t _{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.24	ns
t _{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.46	ns
t _{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.46	ns
t _{CKMPWH}	Clock Minimum Pulse Width HIGH for the Core Register	0.95	ns
t _{CKMPWL}	Clock Minimum Pulse Width LOW for the Core Register	0.95	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-70. Table 2-88 to Table 2-96 on page 2-68 present minimum and maximum global clock delays within each device. Minimum and maximum delays are measured with minimum and maximum loading.

Timing Characteristics

1.5 V DC Core Voltage

Table 2-88 • AGLN010 Global Resource

Commercial-Case Conditions: T_{.I} = 70°C, VCC = 1.425 V

		S	Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.13	1.42	ns
t _{RCKH}	Input High Delay for Global Clock	1.15	1.50	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.35	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-89 • AGLN015 Global Resource Commercial-Case Conditions: T_{.I} = 70°C, VCC = 1.425 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.21	1.55	ns
t _{RCKH}	Input High Delay for Global Clock	1.23	1.65	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.42	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Table 2-92 • AGLN125 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.36	1.71	ns
t _{RCKH}	Input High Delay for Global Clock	1.39	1.82	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.43	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-93 • AGLN250 Global Resource Commercial-Case Conditions: T_{.I} = 70°C, VCC = 1.425 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.39	1.73	ns
t _{RCKH}	Input High Delay for Global Clock	1.41	1.84	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.43	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Table 2-103 • RAM512X18

Commercial-Case Conditions: $T_J = 70$ °C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{AS}	Address setup time	0.69	ns
t _{AH}	Address hold time	0.13	ns
t _{ENS}	REN, WEN setup time	0.61	ns
t _{ENH}	REN, WEN hold time	0.07	ns
t _{DS}	Input data (WD) setup time	0.59	ns
t _{DH}	Input data (WD) hold time	0.30	ns
t _{CKQ1}	Clock HIGH to new data valid on RD (output retained)	3.51	ns
t _{CKQ2}	Clock HIGH to new data valid on RD (pipelined)	1.43	ns
t _{C2CRWH} 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.35	ns
t _{C2CWRH} 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	0.42	ns
t _{RSTBQ}	RESET Low to data out Low on RD (flow-through)	1.72	ns
	RESET Low to data out Low on RD (pipelined)	1.72	ns
t _{REMRSTB}	RESET removal	0.51	0.51
t _{RECRSTB}	RESET recovery	2.68	ns
t _{MPWRSTB}	RESET minimum pulse width	0.68	ns
t _{CYC}	Clock cycle time	6.24	ns
F _{MAX}	Maximum frequency	160	MHz

Notes:

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For more information, refer to the application note AC374: Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based FPGAs and SoC FPGAs App Note.

^{2.} For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



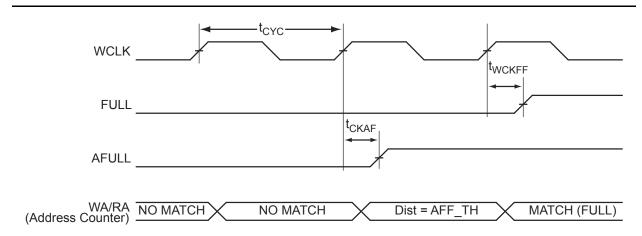


Figure 2-38 • FIFO FULL Flag and AFULL Flag Assertion

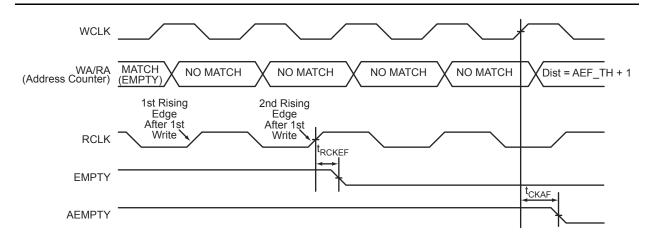


Figure 2-39 • FIFO EMPTY Flag and AEMPTY Flag Deassertion

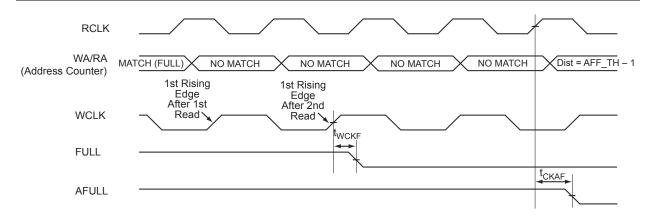


Figure 2-40 • FIFO FULL Flag and AFULL Flag Deassertion

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IGLOO nano Low Power Flash FPGAs

Timing Characteristics

1.5 V DC Core Voltage

Table 2-106 • FIFO

Worst Commercial-Case Conditions: $T_J = 70$ °C, VCC = 1.425 V

Parameter	Description	Std.	Units
t _{ENS}	REN, WEN Setup Time	1.66	ns
t _{ENH}	REN, WEN Hold Time	0.13	ns
t _{BKS}	BLK Setup Time	0.30	ns
t _{BKH}	BLK Hold Time	0.00	ns
t _{DS}	Input Data (WD) Setup Time	0.63	ns
t _{DH}	Input Data (WD) Hold Time	0.20	ns
t _{CKQ1}	Clock High to New Data Valid on RD (flow-through)	2.77	ns
t _{CKQ2}	Clock High to New Data Valid on RD (pipelined)	1.50	ns
t _{RCKEF}	RCLK High to Empty Flag Valid	2.94	ns
t _{WCKFF}	WCLK High to Full Flag Valid	2.79	ns
t _{CKAF}	Clock High to Almost Empty/Full Flag Valid	10.71	ns
t _{RSTFG}	RESET Low to Empty/Full Flag Valid	2.90	ns
t _{RSTAF}	RESET Low to Almost Empty/Full Flag Valid	10.60	ns
t _{RSTBQ}	RESET Low to Data Out LOW on RD (flow-through)	1.68	ns
	RESET Low to Data Out LOW on RD (pipelined)	1.68	ns
t _{REMRSTB}	RESET Removal	0.51	ns
t _{RECRSTB}	RESET Recovery	2.68	ns
t _{MPWRSTB}	RESET Minimum Pulse Width	0.68	ns
t _{CYC}	Clock Cycle Time	6.24	ns
F _{MAX}	Maximum Frequency for FIFO	160	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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should be treated as a sensitive asynchronous signal. When defining pin placement and board layout, simultaneously switching outputs (SSOs) and their effects on sensitive asynchronous pins must be considered.

Unused FF or I/O pins are tristated with weak pull-up. This default configuration applies to both Flash*Freeze mode and normal operation mode. No user intervention is required.

Table 3-1 shows the Flash*Freeze pin location on the available packages for IGLOO nano devices. The Flash*Freeze pin location is independent of device (except for a PQ208 package), allowing migration to larger or smaller IGLOO nano devices while maintaining the same pin location on the board. Refer to the "Flash*Freeze Technology and Low Power Modes" chapter of the IGLOO nano FPGA Fabric User's Guide for more information on I/O states during Flash*Freeze mode.

Table 3-1 • Flash*Freeze Pin Locations for IGLOO nano Devices

Package	Flash*Freeze Pin
CS81/UC81	H2
QN48	14
QN68	18
VQ100	27
UC36	E2

JTAG Pins

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements. Refer to Table 3-2 for more information.

Table 3-2 • Recommended Tie-Off Values for the TCK and TRST Pins

VJTAG	Tie-Off Resistance 1,2
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 k Ω

Notes:

- 1. The TCK pin can be pulled-up or pulled-down.
- 2. The TRST pin is pulled-down.
- 3. Equivalent parallel resistance if more than one device is on the JTAG chain

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Pin Descriptions

Table 3-3 • TRST and TCK Pull-Down Recommendations

VJTAG	Tie-Off Resistance*
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Note: Equivalent parallel resistance if more than one device is on the JTAG chain

TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

TMS Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

TRST Boundary Scan Reset Pin

The TRST pin functions as an active-low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 3-2 and must satisfy the parallel resistance value requirement. The values in Table 3-2 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entrance to an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements.

Special Function Pins

NC No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

DC Do Not Connect

This pin should not be connected to any signals on the PCB. These pins should be left unconnected.

Packaging

Semiconductor technology is constantly shrinking in size while growing in capability and functional integration. To enable next-generation silicon technologies, semiconductor packages have also evolved to provide improved performance and flexibility.

Microsemi consistently delivers packages that provide the necessary mechanical and environmental protection to ensure consistent reliability and performance. Microsemi IC packaging technology efficiently supports high-density FPGAs with large-pin-count Ball Grid Arrays (BGAs), but is also flexible enough to accommodate stringent form factor requirements for Chip Scale Packaging (CSP). In addition, Microsemi offers a variety of packages designed to meet your most demanding application and economic requirements for today's embedded and mobile systems.

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Related Documents

User Guides

IGLOO nano FPGA Fabric User's Guide

Packaging Documents

The following documents provide packaging information and device selection for low power flash devices.

Product Catalog

FPGA and SoC Product Catalog

Lists devices currently recommended for new designs and the packages available for each member of the family. Use this document or the datasheet tables to determine the best package for your design, and which package drawing to use.

Package Mechanical Drawings

This document contains the package mechanical drawings for all packages currently or previously supplied by Microsemi. Use the bookmarks to navigate to the package mechanical drawings.

Additional packaging materials are on the Microsemi SoC Products Group website: http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

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IGLOO nano Low Power Flash FPGAs

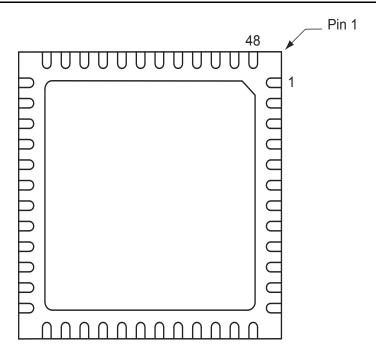
Pin Number AGLN020 Function A1 IO64RSB2 A2 IO54RSB2 A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2		CS81
A2 IO54RSB2 A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND	Pin Number	AGLN020 Function
A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC <t< td=""><td>A1</td><td>IO64RSB2</td></t<>	A1	IO64RSB2
A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A2	IO54RSB2
A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A3	IO57RSB2
A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A4	IO36RSB1
A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A5	IO32RSB1
A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A6	IO24RSB1
A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A7	IO20RSB1
B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A8	IO04RSB0
B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A9	IO08RSB0
B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B1	IO59RSB2
B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B2	IO55RSB2
B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В3	IO62RSB2
B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B4	IO34RSB1
B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B5	IO28RSB1
B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В6	IO22RSB1
B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В7	IO18RSB1
C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B8	IO00RSB0
C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В9	IO03RSB0
C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C1	IO51RSB2
C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C2	IO50RSB2
C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C3	NC
C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C4	NC
C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C5	NC
C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C6	NC
C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C7	NC
D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C8	IO10RSB0
D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C9	IO07RSB0
D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D1	IO49RSB2
D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D2	IO44RSB2
D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D3	NC
D6 GND D7 NC D8 IO13RSB0	D4	VCC
D7 NC D8 IO13RSB0	D5	VCCIB2
D8 IO13RSB0	D6	GND
	D7	NC
D9 IO12RSB0	D8	IO13RSB0
	D9	IO12RSB0

	CS81
Pin Number	AGLN020 Function
E1	GEC0/IO48RSB2
E2	GEA0/IO47RSB2
E3	NC
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	NC
E8	GDA0/IO15RSB0
E9	GDC0/IO14RSB0
F1	IO46RSB2
F2	IO45RSB2
F3	NC
F4	GND
F5	VCCIB1
F6	NC
F7	NC
F8	IO16RSB0
F9	IO17RSB0
G1	IO43RSB2
G2	IO42RSB2
G3	IO41RSB2
G4	IO31RSB1
G5	NC
G6	IO21RSB1
G7	NC
G8	VJTAG
G9	TRST
H1	IO40RSB2
H2	FF/IO39RSB1
H3	IO35RSB1
H4	IO29RSB1
H5	IO26RSB1
H6	IO25RSB1
H7	IO19RSB1
H8	TDI
H9	TDO

CS81		
Pin Number	AGLN020 Function	
J1	IO38RSB1	
J2	IO37RSB1	
J3	IO33RSB1	
J4	IO30RSB1	
J5	IO27RSB1	
J6	IO23RSB1	
J7	TCK	
J8	TMS	
J9	VPUMP	

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QN48



Notes:

- 1. This is the bottom view of the package.
- 2. The die attach paddle of the package is tied to ground (GND).

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

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IGLOO nano Low Power Flash FPGAs

VQ100
AGLN060Z Function
GND
GAA2/IO51RSB1
IO52RSB1
GAB2/IO53RSB1
IO95RSB1
GAC2/IO94RSB1
IO93RSB1
IO92RSB1
GND
GFB1/IO87RSB1
GFB0/IO86RSB1
VCOMPLF
GFA0/IO85RSB1
VCCPLF
GFA1/IO84RSB1
GFA2/IO83RSB1
VCC
VCCIB1
GEC1/IO77RSB1
GEB1/IO75RSB1
GEB0/IO74RSB1
GEA1/IO73RSB1
GEA0/IO72RSB1
VMV1
GNDQ
GEA2/IO71RSB1
FF/GEB2/IO70RSB1
GEC2/IO69RSB1
IO68RSB1
IO67RSB1
IO66RSB1
IO65RSB1
IO65RSB1 IO64RSB1

	VQ100
Pin Number	AGLN060Z Function
35	IO62RSB1
36	IO61RSB1
37	VCC
38	GND
39	VCCIB1
40	IO60RSB1
41	IO59RSB1
42	IO58RSB1
43	IO57RSB1
44	GDC2/IO56RSB1
45*	GDB2/IO55RSB1
46	GDA2/IO54RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO49RSB0
58	GDC0/IO46RSB0
59	GDC1/IO45RSB0
60	GCC2/IO43RSB0
61	GCB2/IO42RSB0
62	GCA0/IO40RSB0
63	GCA1/IO39RSB0
64	GCC0/IO36RSB0
65	GCC1/IO35RSB0
66	VCCIB0
67	GND
68	VCC

VQ100		
Pin Number	AGLN060Z Function	
69	IO31RSB0	
70	GBC2/IO29RSB0	
71	GBB2/IO27RSB0	
72	IO26RSB0	
73	GBA2/IO25RSB0	
74	VMV0	
75	GNDQ	
76	GBA1/IO24RSB0	
77	GBA0/IO23RSB0	
78	GBB1/IO22RSB0	
79	GBB0/IO21RSB0	
80	GBC1/IO20RSB0	
81	GBC0/IO19RSB0	
82	IO18RSB0	
83	IO17RSB0	
84	IO15RSB0	
85	IO13RSB0	
86	IO11RSB0	
87	VCCIB0	
88	GND	
89	VCC	
90	IO10RSB0	
91	IO09RSB0	
92	IO08RSB0	
93	GAC1/IO07RSB0	
94	GAC0/IO06RSB0	
95	GAB1/IO05RSB0	
96	GAB0/IO04RSB0	
97	GAA1/IO03RSB0	
98	GAA0/IO02RSB0	
99	IO01RSB0	
100	IO00RSB0	

Note: *The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin 45 in AGLN060Z-VQ100.

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5 - Datasheet Information

List of Changes

The following table lists critical changes that were made in each version of the IGLOO nano datasheet.

Revision	Changes	Page
Revision 19 (October 2015)	Modified the note to include device/package obsoletion information in "Features and Benefits" section (SAR 69724).	1-I
	Added a note under Security Feature "Y" in "IGLOO nano Ordering Information" section (SAR 70553).	1-IV
	Modified AGLN250 pin assignment table to match with I/O Attribute Editor tool from Libero in "CS81" Package (SAR 59049).	4-6
	Modified the nominal area to 25 for CS81 Package in Table 1 (SAR 71127).	1-II
	Modified the title of AGLN125Z pin assignment table for "CS81" Package (SAR 71127).	4-6
Revision 18 (November 2013)	Modified the "Device Marking" section and updated Figure 1 • Example of Device Marking for Small Form Factor Packages to reflect updates suggested per CN1004 published on 5/10/2010 (SAR 52036).	٧
Revision 17 (May 2013)	Deleted details related to Ambient temperature from "Enhanced Commercial Temperature Range", "IGLOO nano Ordering Information", "Temperature Grade Offerings", and Table 2-2 • Recommended Operating Conditions ¹ to remove ambiguities arising due to the same, and modified Note 2 (SAR 47063).	I, IV, VI, and 2-2
Revision 16 (December 2012)	The "IGLOO nano Ordering Information" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43174).	IV
	The note in Table 2-100 • IGLOO nano CCC/PLL Specification and Table 2-101 • IGLOO nano CCC/PLL Specification referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42565).	2-70, 2-71
	Live at Power-Up (LAPU) has been replaced with 'Instant On'.	NA
	The status of the AGLN125 device has been modified from 'Advance' to 'Production' in the "IGLOO nano Device Status" section (SAR 41416).	III
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 40274).	NA
Revision 14 (September 2012)	The "Security" section was modified to clarify that Microsemi does not support read-back of programmed data.	1-2
Revision 13 (June 2012)	Figure Figure 2-34 • FIFO Read and Figure 2-35 • FIFO Write have been added (SAR 34842).	2-82
	The following sentence was removed from the "VMVx I/O Supply Voltage (quiet)" section in the "Pin Descriptions" section: "Within the package, the VMV plane is decoupled from the simultaneous switching noise originating from the output buffer VCCI domain" and replaced with "Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks" (SAR 38319). The datasheet mentions that "VMV pins must be connected to the corresponding VCCI pins" for an ESD enhancement.	3-1

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